MOSFET – Power, Dual, N-Channel, for 1-2 Cells Lithium-ion Battery Protection 24 V, 2.95 m Ω , 25 A



ON Semiconductor®

www.onsemi.com

V _{SSS}	R _{SS(ON)} MAX	I _S MAX
24 V	2.95 mΩ @ 4.5 V	25 A
	3.0 mΩ @ 3.8 V	
	4.7 mΩ @ 3.1 V	
	7.4 mΩ @ 2.5 V	

Introduction

This Power MOSFET features a low on-state resistance. This device is suitable for applications such as power switches of portable machines. Best suited for 1-2 cells lithium-ion battery applications.

Features

- 2.5 V Drive
- 2 kV ESD HBM
- Common-Drain Type
- ESD Diode-Protected Gate
- This Device is Pb-Free, Halogen Free/BFR Free and is RoHS Compliant

Applications

• 1-2 Cells Lithium-ion Battery Charging and Discharging Switch

Specifications

ABSOLUTE MAXIMUM RATINGS (T_A = 25°C) (Note 1)

Parameter	Symbol	Value	Unit
Source to Source Voltage	V _{SSS}	24	V
Gate to Source Voltage	V _{GSS}	±12	V
Source Current (DC)	I _S	25	Α
Source Current (Pulse) PW ≤ 10 μs, duty cycle ≤ 1%	I _{SP}	100	Α
Total Dissipation (Note 1)	P _T	2.5	W
Junction Temperature	Tj	150	°C
Storage Temperature	T _{stg}	-55 to +150	°C

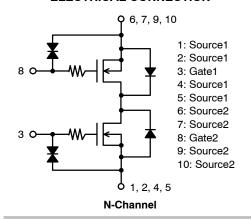
Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

THERMAL RESISTANCE RATINGS

Parameter	Symbol	Value	Unit
Junction to Ambient (Note 1)	$R_{\theta JA}$	50	°C/W

^{1.} Surface mounted on ceramic substrate (5000 $\text{mm}^2 \times 0.8 \text{ mm}$).

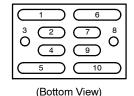
ELECTRICAL CONNECTION



PIN ASSIGNMENT



WLCSP10 (3.20 x 2.10 x 0.14) CASE 567XT



MARKING DIAGRAM



PH = Specific Device Code
A = Assembly Location
Y

Y = Year W = Work Week ZZ = Assembly Lot

ORDERING INFORMATION

See detailed ordering and shipping information on page 5 of this data sheet.

ELECTRICAL CHARACTERISTICS (T_A = 25°C)

Parameter	Symbol	Conditions	Min	Тур	Max	Unit
Source to Source Breakdown Voltage	V _{(BR)SSS}	I _S = 1 mA, V _{GS} = 0 V	24			V
Zero-Gate Voltage Source Current	I _{SSS}	V _{SS} = 19.2 V, V _{GS} = 0 V			1	μΑ
Gate to Source Leakage Current	I _{GSS}	$V_{GS} = \pm 8 \text{ V}, V_{SS} = 0 \text{ V}$			±10	μΑ
Gate Threshold Voltage	V _{GS} (th)	V _{SS} = 10 V, I _S = 1 mA	0.4		1.3	V
Static Source to Source On-State	R _{SS} (on)	I _S = 5 A, V _{GS} = 4.5 V	1.6	2.4	2.95	mΩ
Resistance		I _S = 5 A, V _{GS} = 3.8 V	1.7	2.5	3.0	mΩ
		I _S = 5 A, V _{GS} = 3.1 V	2.0	2.9	4.7	mΩ
		I _S = 5 A, V _{GS} = 2.5 V	2.2	3.6	7.4	mΩ
Gate Resistance	Rg	f = 1 MHz		310		Ω
Total Gate Charge	Qg	V _{SS} = 11.5 V, V _{GS} = 4.5 V, I _S = 5 A		49		nC
Turn-ON Delay Time	t _d (on)	V_{SS} = 11.5 V, V_{GS} = 4.5 V, R_L = 2.3 Ω		0.6		μs
Rise Time	t _r	$R_G = 0 \Omega$ Switching Test Circuit		1.6		μs
Turn-OFF Delay Time	t _d (off)			7.3		μs
Fall Time	t _f			3.2		μs
Forward Source to Source Voltage	V _{F(S-S)}	I _S = 3 A, V _{GS} = 0 V		0.75	1.2	V

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

SWITCHING TEST CIRCUIT

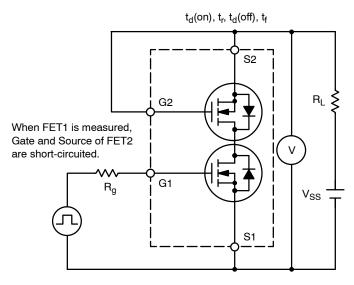
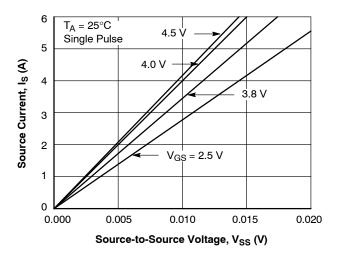


Figure 1. Switching Test Circuit

DEPENDENCY FIGURES

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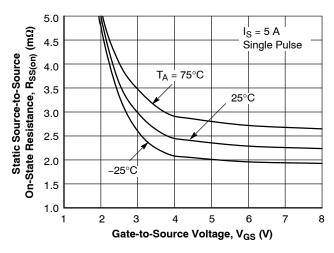
 $V_{SS} = 6 \text{ V}$



9 Single Pulse 8 Source Current, I_S (A) T_A = 75°C 7 6 25°C 5 4 –25°Ċ 3 2 0 0.0 0.2 0.4 0.6 0.8 1.0 1.2 1.4 1.6 1.8 Gate-to-Source Voltage, V_{GS} (V)

Figure 2. On-Region Characteristics

Figure 3. Transfer Characteristics



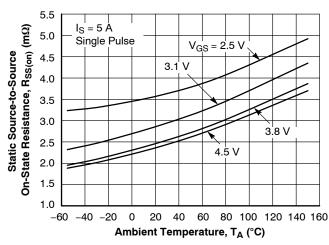
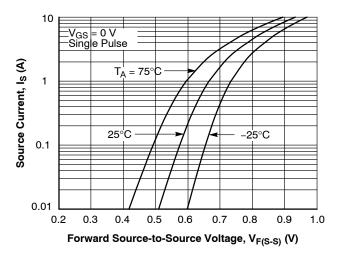


Figure 4. On-Resistance vs. Gate-to-Source Voltage

Figure 5. On-Resistance vs. Temperature



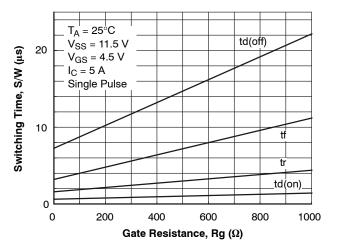
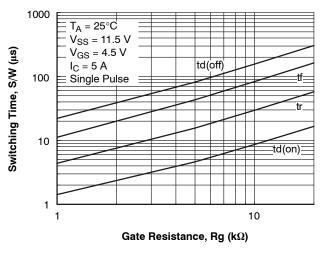


Figure 6. Forward Source-to-Source Voltage vs. Current

Figure 7. Switching Time vs. Gate Resistance (1)

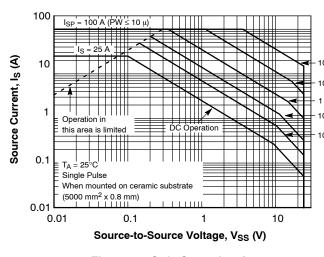
4.5



 $T_A = 25^{\circ}C$ 4.0 S V_{SS} = 11.5 V Gate-to-Source Voltage, VGS $I_S = 5 A$ 3.5 3.0 2.5 2.0 1.5 1.0 0.5 0.0 0 10 20 30 40 50 60 Total Gate Charge, Qg (nC)

Figure 8. Switching Time vs. Gate Resistance (2)

Figure 9. Gate-to-Source Voltage vs.
Total Charge



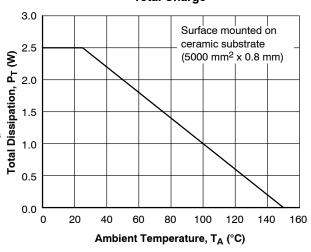


Figure 10. Safe Operating Area

Figure 11. Total Dissipation vs. Temperature

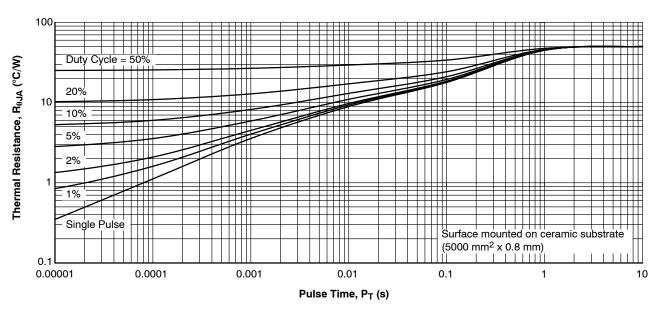


Figure 12. Thermal Response

ORDERING INFORMATION

Device	Marking	Package	Shipping [†] (Qty / Packing)
EFC4K110NUZTDG	РН	WLCSP10, 3.20 x 2.10 x 0.14 (Pb-Free / Halogen Free)	5000 / Tape & Reel

[†]For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

Note on usage: Since the EFC4K110NUZ is a MOSFET product, please avoid using this device in the vicinity of highly charged objects.



PAD 1

REFERENCE

WLCSP10 3.2x2.1x0.14

CASE 567XT **ISSUE O**

В

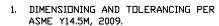
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Α

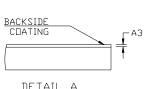
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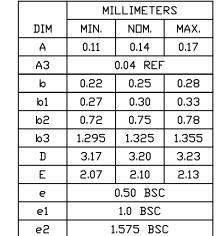
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DATE 02 APR 2019

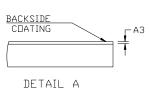


- 2. CONTROLLING DIMENSION: MILLIMETERS
- POSITIONAL TOLERANCE APPLIES TO ALL PADS.





2.50 BSC



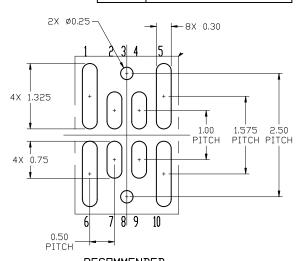
	SIDE VIEW
2X (+)0.05()) C NOTE 3	8
4X k3	7 9 + + + + + + + + + + + + + + + + + +
4X b2	e1 e2 e3

TOP VIEW

DETAIL A

// 0.03 C

0.03 C



e3

RECOMMENDED MOUNTING FOOTPRINT*

For additional information on our Pb-Free strategy and soldering details, please download the IN Semiconductor Soldering and Mounting Techniques Reference Manual, SDLDERRM/D.

*This information is generic. Please refer to device data sheet for actual part marking. Pb-Free indicator, "G" or microdot "=", may or may not be present. Some products may not follow the Generic Marking.

XX
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BOTTOM VIEW

GENERIC MARKING DIAGRAM* XX = Specific Device Code Α = Assembly Location = Year

W = Work Week

ZZ = Assembly Lot Code = Pb-Free Package

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DESCRIPTION: WLCSP10 3.2x2.1x0.14 PAGE 1 OF 1

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